

MUN2214, MMUN2214L, MUN5214, DTC114YE, DTC114YM3, NSBC114YF3

Digital Transistors (BRT) R1 = 10 kΩ, R2 = 47 kΩ

NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

| Rating | Symbol | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage | V _{CBO} | 50 | Vdc |
| Collector-Emitter Voltage | V _{CEO} | 50 | Vdc |
| Collector Current - Continuous | I _C | 100 | mAdc |
| Input Forward Voltage | V _{IN(fwd)} | 40 | Vdc |
| Input Reverse Voltage | V _{IN(rev)} | 6 | Vdc |

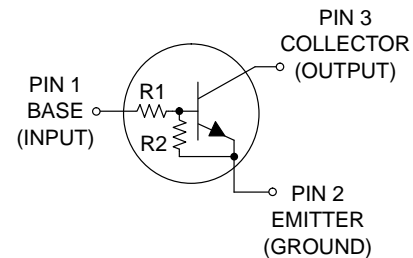
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



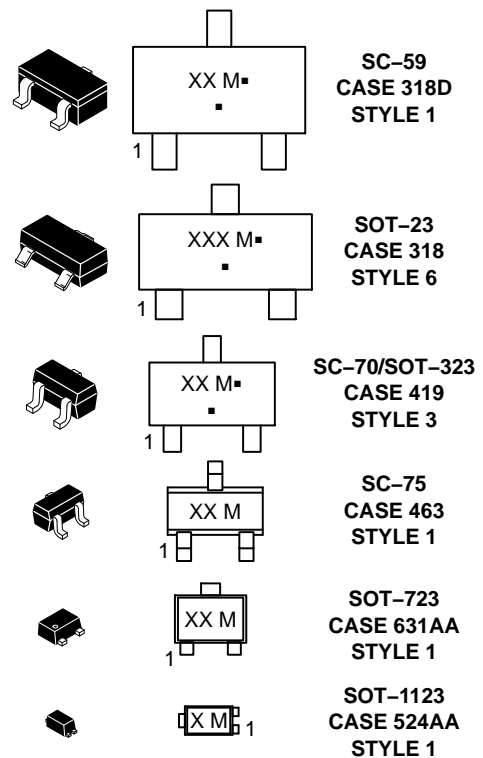
ON Semiconductor®

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PIN CONNECTIONS



MARKING DIAGRAMS



XXX = Specific Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

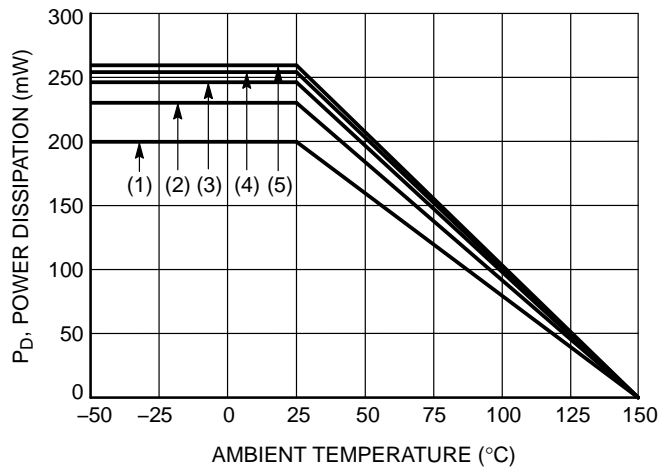
MUN2214, MMUN2214L, MUN5214, DTC114YE, DTC114YM3, NSBC114YF3

Table 1. ORDERING INFORMATION

| Device | Part Marking | Package | Shipping† |
|-----------------------------------|--------------|----------------------------|---------------------|
| MUN2214T1G, SMUN2214T1G* | 8D | SC-59 (Pb-Free) | 3000 / Tape & Reel |
| MUN2214T3G, SMUN2214T3G* | 8D | SC-59 (Pb-Free) | 10000 / Tape & Reel |
| MMUN2214LT1G, SMMUN2214LT1G* | A8D | SOT-23 (Pb-Free) | 3000 / Tape & Reel |
| MUN5214T1G, SMUN5214T1G* | 8D | SC-70/SOT-323 (Pb-Free) | 3000 / Tape & Reel |
| DTC114YET1G, SDTC114YET1G | 8D | SC-75 (Pb-Free) | 3000 / Tape & Reel |
| DTC114YM3T5G, NSVDTC114YM3T5G* | 8D | SOT-723 (Pb-Free) | 8000 / Tape & Reel |
| NSBC114YF3T5G | J | SOT-1123 (Pb-Free) | 8000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



- (1) SC-75 and SC-70/SOT-323; Minimum Pad
- (2) SC-59; Minimum Pad
- (3) SOT-23; Minimum Pad
- (4) SOT-1123; 100 mm², 1 oz. copper trace
- (5) SOT-723; Minimum Pad

Figure 1. Derating Curve

MUN2214, MMUN2214L, MUN5214, DTC114YE, DTC114YM3, NSBC114YF3

Table 2. THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------|-------------|-------|
| THERMAL CHARACTERISTICS (SC-59) (MUN2214) | | | |
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | P_D | 230 | mW |
| Derate above 25°C | | 338 | mW/°C |
| | | 1.8 | |
| | | 2.7 | |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 540 | °C/W |
| | | 370 | |
| Thermal Resistance, Junction to Lead | $R_{\theta JL}$ | 264 | °C/W |
| | | 287 | |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SOT-23) (MMUN2214L) | | | |
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | P_D | 246 | mW |
| Derate above 25°C | | 400 | mW/°C |
| | | 2.0 | |
| | | 3.2 | |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 508 | °C/W |
| | | 311 | |
| Thermal Resistance, Junction to Lead | $R_{\theta JL}$ | 174 | °C/W |
| | | 208 | |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5214) | | | |
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | P_D | 202 | mW |
| Derate above 25°C | | 310 | mW/°C |
| | | 1.6 | |
| | | 2.5 | |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 618 | °C/W |
| | | 403 | |
| Thermal Resistance, Junction to Lead | $R_{\theta JL}$ | 280 | °C/W |
| | | 332 | |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SC-75) (DTC114YE) | | | |
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | P_D | 200 | mW |
| Derate above 25°C | | 300 | mW/°C |
| | | 1.6 | |
| | | 2.4 | |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 600 | °C/W |
| | | 400 | |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SOT-723) (DTC114YM3) | | | |
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | P_D | 260 | mW |
| Derate above 25°C | | 600 | mW/°C |
| | | 2.0 | |
| | | 4.8 | |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 480 | °C/W |
| | | 205 | |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | °C |

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 Inch Pad.
3. FR-4 @ 100 mm², 1 oz. copper traces, still air.
4. FR-4 @ 500 mm², 1 oz. copper traces, still air.

MUN2214, MMUN2214L, MUN5214, DTC114YE, DTC114YM3, NSBC114YF3

Table 2. THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|---|--------------------------|--------------------------------|
| THERMAL CHARACTERISTICS (SOT-1123) (NSBC114YF3) | | | |
| Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D (Note 3) (Note 4) (Note 3) (Note 4) | 254 297 2.0 2.4 | mW mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ (Note 3) (Note 4) | 493 421 | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction to Lead | $R_{\theta JL}$ (Note 3) | 193 | $^\circ\text{C/W}$ |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

- FR-4 @ Minimum Pad.
- FR-4 @ 1.0 x 1.0 Inch Pad.
- FR-4 @ 100 mm², 1 oz. copper traces, still air.
- FR-4 @ 500 mm², 1 oz. copper traces, still air.

Table 3. ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|---------------|------|------|------|------------|
| OFF CHARACTERISTICS | | | | | |
| Collector-Base Cutoff Current ($V_{CB} = 50\text{ V}, I_E = 0$) | I_{CBO} | - | - | 100 | nAdc |
| Collector-Emitter Cutoff Current ($V_{CE} = 50\text{ V}, I_B = 0$) | I_{CEO} | - | - | 500 | nAdc |
| Emitter-Base Cutoff Current ($V_{EB} = 6.0\text{ V}, I_C = 0$) | I_{EBO} | - | - | 0.2 | mAdc |
| Collector-Base Breakdown Voltage ($I_C = 10\ \mu\text{A}, I_E = 0$) | $V_{(BR)CBO}$ | 50 | - | - | Vdc |
| Collector-Emitter Breakdown Voltage (Note 5) ($I_C = 2.0\text{ mA}, I_B = 0$) | $V_{(BR)CEO}$ | 50 | - | - | Vdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain (Note 5) ($I_C = 5.0\text{ mA}, V_{CE} = 10\text{ V}$) | h_{FE} | 80 | 140 | - | |
| Collector - Emitter Saturation Voltage (Note 5) ($I_C = 10\text{ mA}, I_B = 0.3\text{ mA}$) | $V_{CE(sat)}$ | - | - | 0.25 | Vdc |
| Input Voltage (off) ($V_{CE} = 5.0\text{ V}, I_C = 100\ \mu\text{A}$) | $V_{i(off)}$ | - | 0.7 | 0.5 | Vdc |
| Input Voltage (on) ($V_{CE} = 0.3\text{ V}, I_C = 1.0\text{ mA}$) | $V_{i(on)}$ | 1.4 | 0.8 | - | Vdc |
| Output Voltage (on) ($V_{CC} = 5.0\text{ V}, V_B = 2.5\text{ V}, R_L = 1.0\text{ k}\Omega$) | V_{OL} | - | - | 0.2 | Vdc |
| Output Voltage (off) ($V_{CC} = 5.0\text{ V}, V_B = 0.5\text{ V}, R_L = 1.0\text{ k}\Omega$) | V_{OH} | 4.9 | - | - | Vdc |
| Input Resistor | R_1 | 7.0 | 10 | 13 | k Ω |
| Resistor Ratio | R_1/R_2 | 0.17 | 0.21 | 0.25 | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Pulsed Condition: Pulse Width = 300 msec, Duty Cycle $\leq 2\%$.

TYPICAL CHARACTERISTICS
MUN2214, MMUN2214L, MUN5214, DTC114YE, DTC114YM3



Figure 2. $V_{CE(sat)}$ vs. I_C



Figure 3. DC Current Gain

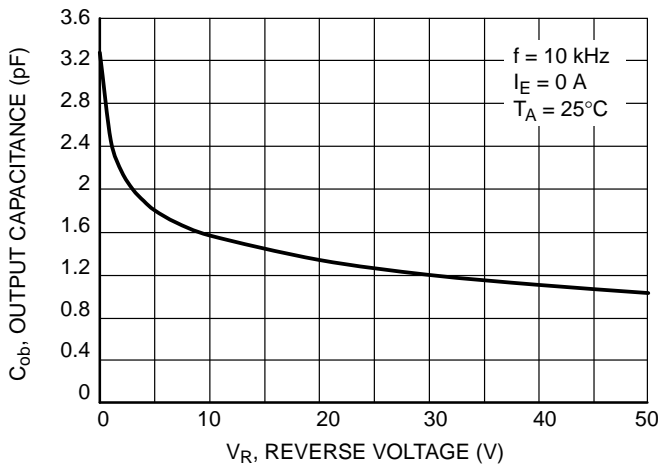


Figure 4. Output Capacitance

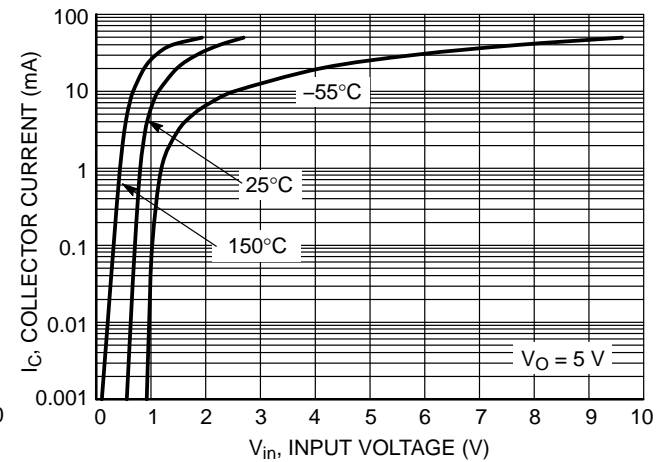


Figure 5. Output Current vs. Input Voltage

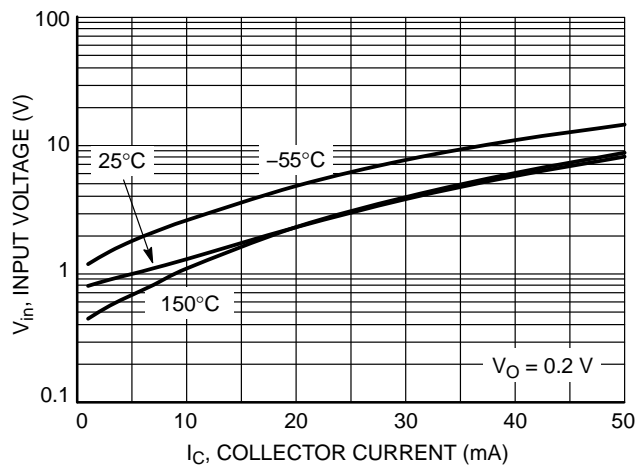


Figure 6. Input Voltage vs. Output Current

TYPICAL CHARACTERISTICS
NSBC114YF3

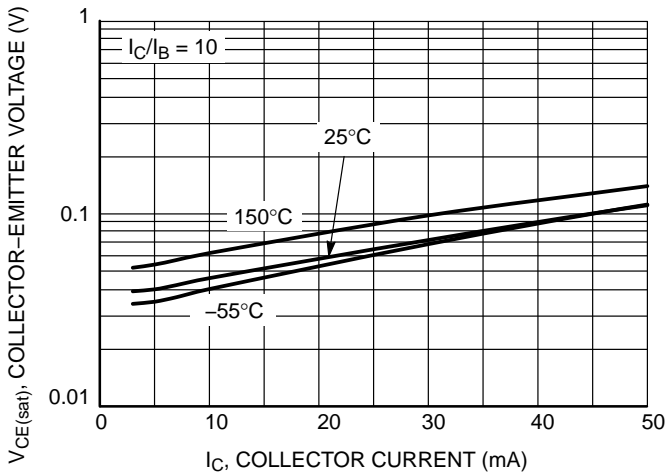


Figure 7. $V_{CE(sat)}$ vs. I_C

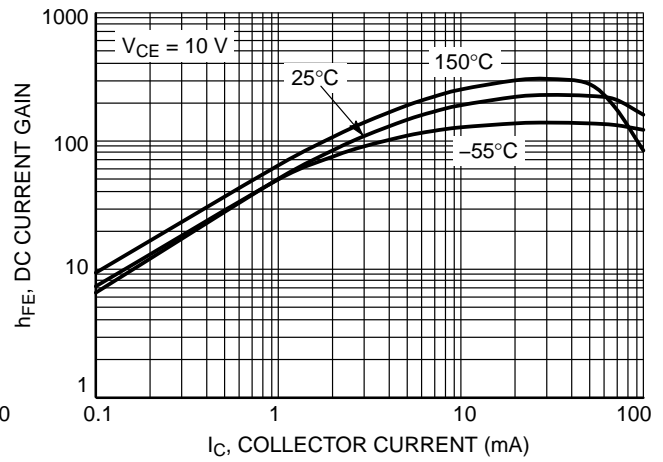


Figure 8. DC Current Gain

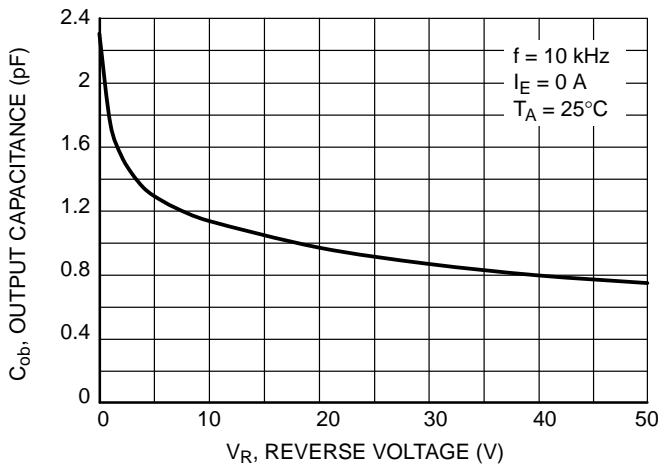


Figure 9. Output Capacitance

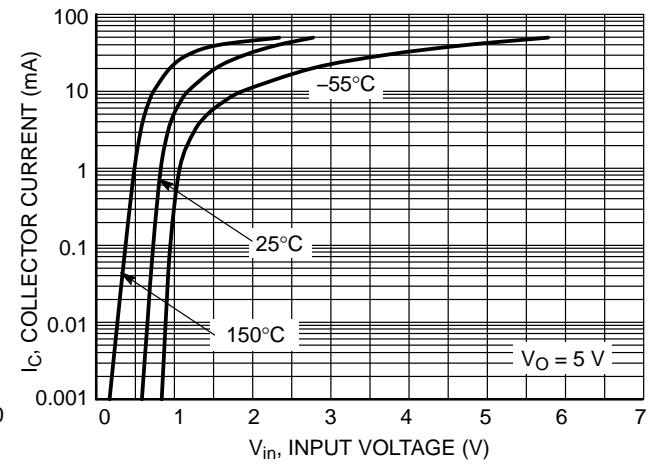


Figure 10. Output Current vs. Input Voltage

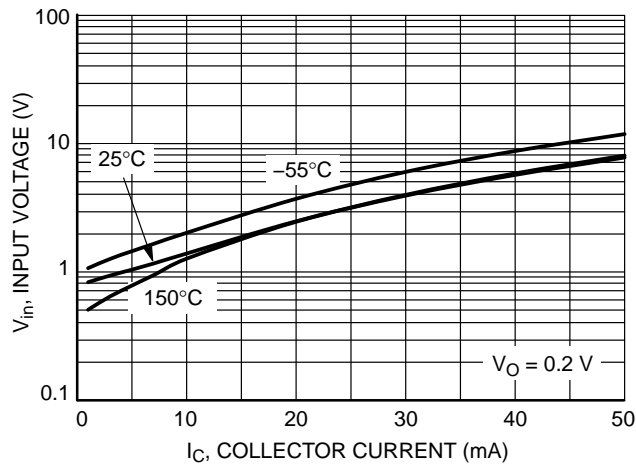


Figure 11. Input Voltage vs. Output Current

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 4:1

SC-70 (SOT-323) CASE 419 ISSUE R

DATE 11 OCT 2022



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH

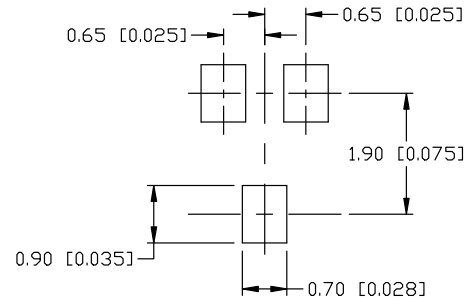
| DIM | MILLIMETERS | | | INCHES | | |
|----------------|-------------|------|------|-----------|-------|-------|
| | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 0.80 | 0.90 | 1.00 | 0.032 | 0.035 | 0.040 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| A2 | 0.70 REF | | | 0.028 BSC | | |
| b | 0.30 | 0.35 | 0.40 | 0.012 | 0.014 | 0.016 |
| c | 0.10 | 0.18 | 0.25 | 0.004 | 0.007 | 0.010 |
| D | 1.80 | 2.00 | 2.20 | 0.071 | 0.080 | 0.087 |
| E | 1.15 | 1.24 | 1.35 | 0.045 | 0.049 | 0.053 |
| e | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e1 | 0.65 BSC | | | 0.026 BSC | | |
| L | 0.20 | 0.38 | 0.56 | 0.008 | 0.015 | 0.022 |
| H _E | 2.00 | 2.10 | 2.40 | 0.079 | 0.083 | 0.095 |

GENERIC MARKING DIAGRAM



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.



* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

SOLDERING FOOTPRINT

- | | | | | | |
|---|---|---|--|---|---|
| STYLE 1: CANCELLED | STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE | STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE | |
| STYLE 6: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 7: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 8: PIN 1. GATE 2. SOURCE 3. DRAIN | STYLE 9: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE | STYLE 10: PIN 1. CATHODE 2. ANODE 3. ANODE-CATHODE | STYLE 11: PIN 1. CATHODE 2. CATHODE 3. CATHODE |

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| DESCRIPTION: | SC-70 (SOT-323) | PAGE 1 OF 1 |

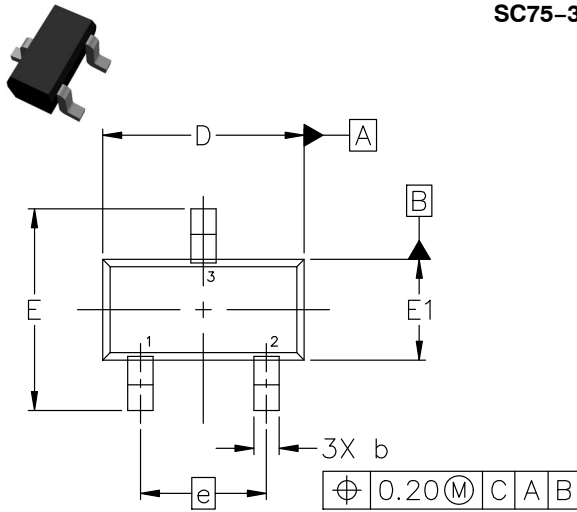
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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

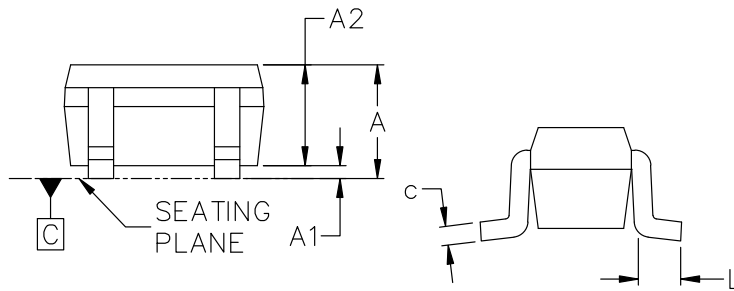


SC75-3 1.60x0.80x0.80, 1.00P
CASE 463
ISSUE H

DATE 01 FEB 2024



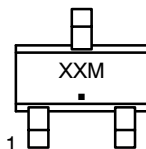
TOP VIEW



SIDE VIEW

END VIEW

GENERIC MARKING DIAGRAM*



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

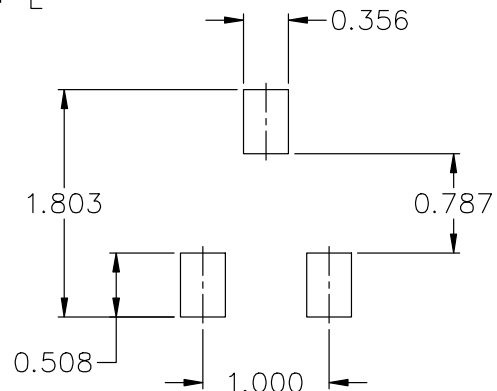
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

- STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR
- STYLE 2:
PIN 1. ANODE
2. N/C
3. CATHODE
- STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE
- STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE
- STYLE 5:
PIN 1. GATE
2. SOURCE
3. DRAIN

NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS.

| DIM | MILLIMETERS | | |
|-----|-------------|------|------|
| | MIN. | NOM. | MAX. |
| A | 0.70 | 0.80 | 0.90 |
| A1 | 0.00 | 0.05 | 0.10 |
| A2 | 0.80 REF. | | |
| b | 0.15 | 0.20 | 0.30 |
| c | 0.10 | 0.15 | 0.25 |
| D | 1.55 | 1.60 | 1.65 |
| E | 1.50 | 1.60 | 1.70 |
| E1 | 0.70 | 0.80 | 0.90 |
| e | 1.00 BSC | | |
| L | 0.10 | 0.15 | 0.20 |



RECOMMENDED MOUNTING FOOTPRINT*

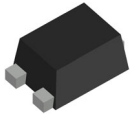
* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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| DESCRIPTION: | SC75-3 1.60x0.80x0.80, 1.00P | PAGE 1 OF 1 |

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



SOT-1123 0.80x0.60x0.37, 0.35P
CASE 524AA
ISSUE D

DATE 18 JAN 2024



TOP VIEW



SIDE VIEW



BOTTOM VIEW

GENERIC MARKING DIAGRAM*



X = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| MILLIMETERS | | | |
|-------------|-----------|-------|-------|
| DIM | MIN | NOM | MAX |
| A | 0.34 | 0.37 | 0.40 |
| b | 0.15 | 0.22 | 0.28 |
| b1 | 0.10 | 0.15 | 0.20 |
| c | 0.07 | 0.12 | 0.17 |
| D | 0.75 | 0.80 | 0.85 |
| E | 0.55 | 0.60 | 0.65 |
| e | 0.35 | 0.38 | 0.40 |
| H | 0.950 | 1.000 | 1.050 |
| L | 0.185 REF | | |
| L2 | 0.05 | 0.10 | 0.15 |



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERM/D.

| | | | | |
|---|--|--|--|--|
| STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE | STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE | STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN |
|---|--|--|--|--|

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| DESCRIPTION: | SOT-1123 0.80x0.60x0.37, 0.35P | PAGE 1 OF 1 |

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



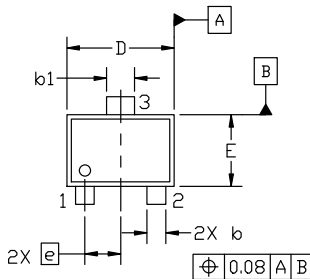
SOT-723 1.20x0.80x0.50, 0.40P
CASE 631AA
ISSUE E

DATE 24 JAN 2024

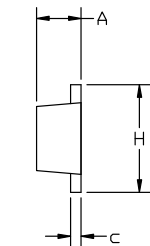
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

| DIM | MILLIMETERS | | |
|-----|-------------|------|------|
| | MIN. | NOM. | MAX. |
| A | 0.45 | 0.50 | 0.55 |
| b | 0.15 | 0.21 | 0.27 |
| b1 | 0.25 | 0.31 | 0.37 |
| c | 0.07 | 0.12 | 0.17 |
| D | 1.15 | 1.20 | 1.25 |
| E | 0.75 | 0.80 | 0.85 |
| e | 0.40 BSC | | |
| H | 1.15 | 1.20 | 1.25 |
| L | 0.29 REF | | |
| L2 | 0.15 | 0.20 | 0.25 |



TOP VIEW



SIDE VIEW



BOTTOM VIEW



RECOMMENDED MOUNTING FOOTPRINT

GENERIC MARKING DIAGRAM*



XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

| STYLE 1: | STYLE 2: | STYLE 3: | STYLE 4: | STYLE 5: |
|--------------|--------------|--------------|----------------|-------------|
| PIN 1. BASE | PIN 1. ANODE | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. GATE |
| 2. EMITTER | 2. N/C | 2. ANODE | 2. CATHODE | 2. SOURCE |
| 3. COLLECTOR | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. DRAIN |

| | | |
|-------------------------|--------------------------------------|--|
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| DESCRIPTION: | SOT-723 1.20x0.80x0.50, 0.40P | PAGE 1 OF 1 |

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